

TPS61099x 静态电流极低的同步升压转换器

1 特性

- 600 nA 超低 I_Q 流入 V_{OUT} 引脚
- 400 nA 超低 I_Q 流入 V_{IN} 引脚
- 工作输入电压范围为 0.7V 至 5.5V
- 可调输出电压范围为 1.8V 至 5.5V
- 提供固定输出电压版本
- 最小开关峰值电流限值为 0.8A
- 降压模式下的稳压输出电压
- 关断期间真正实现断开
- 使用固定输出电压版本时，10 μ A 负载条件下的效率高达 75%
- 在 10mA 至 300mA 负载条件下，效率高达 93%
- 6 球 1.23mm x 0.88mm WCSP 封装和 2mm x 2mm WSON 封装
- 使用 TPS61099x 并借助 [WEBENCH® Power Designer](#) 创建定制设计方案

2 应用

- 存储器液晶显示屏 (LCD) 偏置
- 光学心率监测发光二极管 (LED) 偏置
- 可穿戴设备
- 低功耗无线应用
- 便携式产品
- 电池供电系统

3 说明

TPS61099x 器件是一款具有 1 μ A 超低静态电流的同步升压转换器。该器件专为由碱性电池、镍氢充电电池、锂锰电池或锂离子充电电池供电的产品而设计，能够在轻载条件下高效运行，这对延长电池使用寿命至关重要。

TPS61099x 升压转换器采用迟滞控制拓扑，可在静态电流最低的情况下实现最高效率。该器件在轻载条件下仅消耗 1 μ A 静态电流；当负载为 10 μ A，固定输出电压版本时，可实现高达 75% 的效率。该器件在 3.3V 至 5V 转换过程中的输出电流高达 300mA，在 200mA 负载条件下可实现高达 93% 的效率。

TPS61099x 还可为不同应用提供降压模式和直通模式。在降压模式下，即使输入电压高于输出电压，输出电压仍可调节为目标值。在直通模式下，输出电压随着输入电压发生变化。当 $V_{IN} > V_{OUT} + 0.5V$ 时，TPS61099x 退出降压模式并转入直通模式。

TPS61099x 在禁用状态下能够将负载与输入电源断开，真正实现关断，从而降低电流消耗。

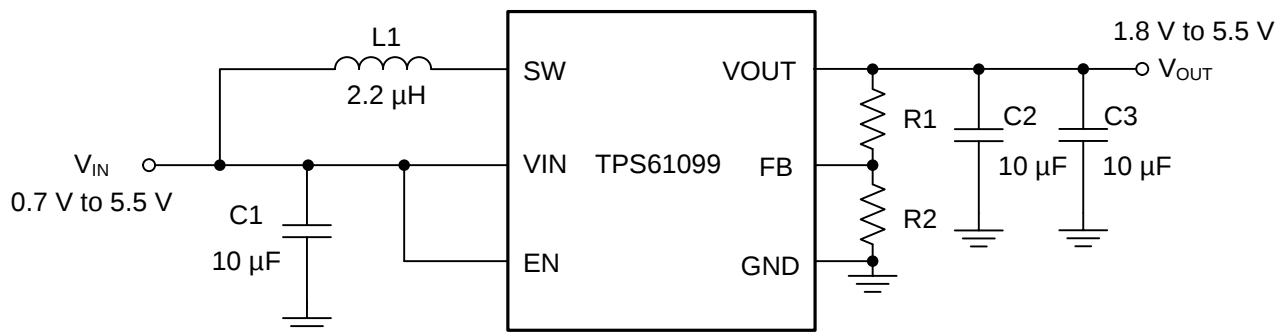
TPS61099x 具有可调输出电压版本和固定输出电压版本。该器件采用 6 焊球 1.23mm x 0.88mm WCSP 封装和 6 引脚 2mm x 2mm WSON 封装。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
TPS61099	WCSP (6)	1.23mm x 0.88mm
TPS61099x		
TPS61099	WSON (6)	2mm x 2mm
TPS61099x		

(1) 如需了解所有可用封装，请参阅本文档末尾的可订购产品附录。

典型应用电路



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4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

Changes from Revision J (October 2017) to Revision K	Page
• 已添加 Load Efficiency graph for TPS610995 device	8

Changes from Revision I (September 2017) to Revision J	Page
• 已更改 将说明 部分中的 +0.3 V 更改成了 +0.5 V	1
• 已更改 graph image for 图 7	8
• 已更改 from +0.3 V to +0.5 V in fourth paragraph of Down Mode Regulation and Pass-Through Operation section	13
• 已更改 Image for 图 20	14

Changes from Revision H (July 2017) to Revision I	Page
• Added devices to the Device Comparison Table and added graphs to Typical Characteristics section.	4

Changes from Revision G (July 2017) to Revision H	Page
• Changed TPS610994 Output accuracy typical value from 3.33 to 3.4 for "VIN < VOUT, PFM mode" in the Electrical Characteristics table.	6
• Changed TPS610993 Output accuracy typical value from 3.03 to 3.1 for "VIN < VOUT, PFM mode" in the Electrical Characteristics table.	6

Changes from Revision F (June 2017) to Revision G	Page
• Added TPS610993 device Output accuracy specs. to Electrical Characteristics table	6

Changes from Revision E (April 2017) to Revision F	Page
• 已删除 删除了产品说明书标题中的电压变型器件	1
• 已添加 <i>TPS610993 Load Efficiency with Different Inputs</i>	8
• 已更改 <i>Functional Block Diagram</i>	11

Changes from Revision D (March 2017) to Revision E	Page
• 已更改 figures 1 and 2: <i>Load Efficiency with Different Inputs</i> , figure 3: <i>TPS610994 Load Efficiency with Different Inputs</i> , and figure 4: <i>Load Efficiency with Different Outputs</i> with new graph data	8

Changes from Revision C (January 2017) to Revision D	Page
• 已更改 text string in the Programming the Output Voltage section, 2nd para From "...the FB pin should be connected to the V _{OUT} pin directly" To "...the FB pin should be connected to the GND"	16

Changes from Revision B (December 2016) to Revision C	Page
• 已添加 WEBENCH® 模型	1
• Added devices to the Device Comparison Table	4
• Added TPS610994 device Output accuracy specs. to Electrical Characteristics table	6
• 已添加 图 5	8
• 已添加 图 15	9

Changes from Revision A (September 2016) to Revision B	Page
• 已添加 器件 TPS610997; 通改	1
• Changed From: "Connect to VOUT pin...." To: " Connect to GND pin...." for C2 pin description in the Pin Configuration and Functions table,	4
• Added Output accuracy spec for TPS610997 device in the Output section of the Electrical Characteristics table	6
• 已添加 图 2 and 图 14	9

Changes from Original (June 2016) to Revision A	Page
• 已添加 完整的产品说明书规格 - 通改	1

TPS61099

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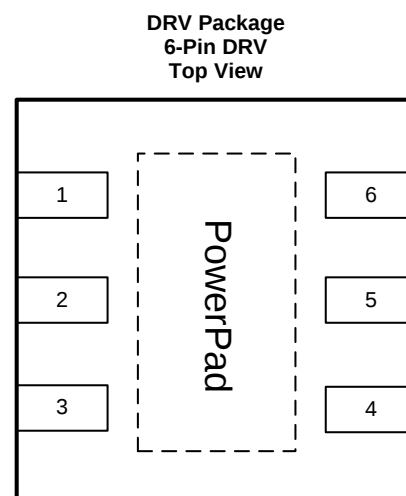
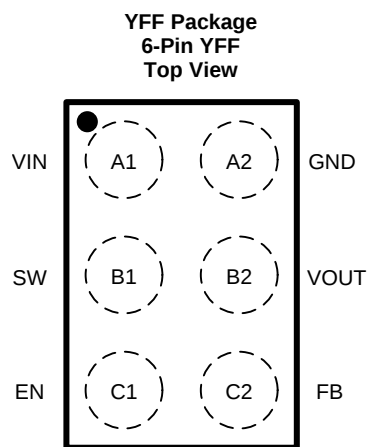
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5 Device Comparison Table

PART NUMBER	OUTPUT VOLTAGE
TPS61099	Adjustable
TPS610997	5.0 V
TPS610996	4.5 V
TPS610995	3.6 V
TPS610994	3.3 V
TPS610993	3.0 V
TPS610992	2.5 V
TPS610991 ⁽¹⁾	1.8 V

(1) Product Preview. Contact TI factory for more information.

6 Pin Configuration and Functions



Pin Functions

PIN			TYPE	DESCRIPTION
NAME	YFF	DRV		
VIN	A1	6	I	IC power supply input
SW	B1	5	PWR	Switch pin of the converter. It is connected to the inductor
EN	C1	4	I	Enable logic input. Logic high voltage enables the device; logic low voltage disables the device. Do not leave it floating.
GND	A2	1	PWR	Ground
VOUT	B2	2	PWR	Boost converter output
FB	C2	3	I	Voltage feedback of adjustable output voltage. Connect to the center tap of a resistor divider to program the output voltage. Connect to GND pin for fixed output voltage versions.
PowerPad		7		Connect to GND

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage range at terminals ⁽²⁾	VIN, SW, VOUT, FB, EN	-0.3	6.0	V
Operating junction temperature, T _J		-40	150	°C
Storage temperature range, T _{stg}		-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to network ground terminal.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human Body Model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	V
	Charged Device Model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500V HBM rating allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM rating allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage range	0.7		5.5	V
V _{OUT}	Output voltage range	1.8		5.5	V
L	Inductor	0.7	2.2	2.86	μH
C _{IN}	Input capacitor	1.0	10		μF
C _{OUT}	Output capacitor	10	20	100	μF
T _J	Operating virtual junction temperature	-40		125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS61099		UNIT
		YFF (6 BALLS, WCSP)	DRV(6 PINS, WSON)	
R _{θJA}	Junction-to-ambient thermal resistance	134.4	71.7	°C/W
R _{θJCTop}	Junction-to-case (top) thermal resistance	0.9	83.0	°C/W
R _{θJB}	Junction-to-board thermal resistance	36.1	33.9	°C/W
ψ _{JT}	Junction-to-top characterization parameter	0.1	2.7	°C/W
ψ _{JB}	Junction-to-board characterization parameter	36.2	33.4	°C/W
R _{θJCbott}	Junction-to-case (bottom) thermal resistance	N/A	14.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953](#).

TPS61099

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7.5 Electrical Characteristics
 $T_J = -40^{\circ}\text{C}$ to 125°C and $V_{IN} = 0.7\text{ V}$ to 5.5 V . Typical values are at $V_{IN} = 3.7\text{ V}$, $T_J = 25^{\circ}\text{C}$, unless otherwise noted.

PARAMETER		Version	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY							
V_{IN}	Input voltage range	TPS61099x		0.7		5.5	V
V_{UVLO}	Input under voltage lockout threshold	TPS61099x	V_{IN} rising		0.6	0.7	V
	UVLO hysteresis	TPS61099x			200		mV
I_Q	Quiescent current into VIN pin	TPS61099x	IC enabled, no Load, no Switching $T_J = -40^{\circ}\text{C}$ to 85°C		0.4	1.1	μA
	Quiescent current into VOUT pin	TPS61099x	IC enabled, no Load, no Switching, Boost or Down Mode $T_J = -40^{\circ}\text{C}$ to 85°C		0.6	1.5	μA
I_{SD}	Shutdown current into VIN pin	TPS61099x	IC disabled, $V_{IN} = 3.7\text{ V}$, $V_{OUT} = 0\text{ V}$ $T_J = -40^{\circ}\text{C}$ to 85°C		0.5	1.6	μA
OUTPUT							
V_{OUT}	Output voltage range	TPS61099		1.8		5.5	V
Output accuracy		TPS610997	$V_{IN} < V_{OUT}$, PWM mode	4.90	5.00	5.10	V
			$V_{IN} < V_{OUT}$, PFM mode		5.15		
		TPS610994	$V_{IN} < V_{OUT}$, PWM mode	3.23	3.30	3.37	V
			$V_{IN} < V_{OUT}$, PFM mode		3.4		
		TPS610993	$V_{IN} < V_{OUT}$, PWM mode	2.94	3.0	3.06	V
			$V_{IN} < V_{OUT}$, PFM mode		3.1		
		TPS610996	$V_{IN} < V_{OUT}$, PWM mode	4.4	4.5	4.6	V
			$V_{IN} < V_{OUT}$, PFM mode		4.63		
		TPS610992	$V_{IN} < V_{OUT}$, PWM mode	2.45	2.5	2.55	V
			$V_{IN} < V_{OUT}$, PFM mode		2.58		
		TPS610995	$V_{IN} < V_{OUT}$, PWM mode	3.53	3.6	3.67	V
			$V_{IN} < V_{OUT}$, PFM mode		3.71		
V_{REF}	Feedback reference voltage	TPS61099	$V_{IN} < V_{OUT}$, PWM mode	0.98	1.00	1.02	V
		TPS61099	$V_{IN} < V_{OUT}$, PFM mode		1.03		V
V_{OVP}	Output overvoltage protection threshold	TPS61099x	V_{OUT} rising	5.6	5.8	6.0	V
	OVP hysteresis	TPS61099x			100	200	mV
I_{FB_LKG}	Leakage current into FB pin	TPS61099x	$V_{FB} = 1.0\text{ V}$		10	50	nA
POWER SWITCH							
$R_{DS(on)_LS}$	Low side switch on resistance	TPS61099x	$V_{OUT} = 5.0\text{ V}$		250		$\text{m}\Omega$
			$V_{OUT} = 3.3\text{ V}$		300		$\text{m}\Omega$
			$V_{OUT} = 1.8\text{ V}$		400		$\text{m}\Omega$
$R_{DS(on)_HS}$	Rectifier on resistance	TPS61099x	$V_{OUT} = 5.0\text{ V}$		300	350	$\text{m}\Omega$
			$V_{OUT} = 3.3\text{ V}$		350	450	$\text{m}\Omega$
			$V_{OUT} = 1.8\text{ V}$		500	750	$\text{m}\Omega$
I_{LH}	Inductor current ripple	TPS61099x	$V_{OUT} = 5.0\text{ V}$		350		mA
			$V_{OUT} = 3.3\text{ V}$		300		mA
			$V_{OUT} = 1.8\text{ V}$		250		mA
I_{LIM}	Current limit threshold	TPS61099x	$V_{OUT} \geq 2.5\text{ V}$, boost operation	0.8	1	1.25	A
			$V_{OUT} < 2.5\text{ V}$, boost operation	0.5	0.75		A
I_{SW_LKG}	Leakage current into SW pin (from SW pin to GND)	TPS61099x	$V_{SW} = 5.0\text{ V}$, no switch, $T_J = -40^{\circ}\text{C}$ to 85°C			200	nA

Electrical Characteristics (continued)

$T_J = -40^{\circ}\text{C}$ to 125°C and $V_{IN} = 0.7\text{ V}$ to 5.5 V . Typical values are at $V_{IN} = 3.7\text{ V}$, $T_J = 25^{\circ}\text{C}$, unless otherwise noted.

PARAMETER		Version	TEST CONDITIONS	MIN	TYP	MAX	UNIT
CONTROL LOGIC							
V_{IL}	EN input low voltage threshold	TPS61099x	$V_{IN} \leq 1.5\text{ V}$	$0.2 \times V_{IN}$			V
V_{IH}	EN input high voltage threshold	TPS61099x	$V_{IN} \leq 1.5\text{ V}$			$0.8 \times V_{IN}$	V
V_{IL}	EN input low voltage threshold	TPS61099x	$V_{IN} > 1.5\text{ V}$	0.4			V
V_{IH}	EN input high voltage threshold	TPS61099x	$V_{IN} > 1.5\text{ V}$			1.2	V
I_{EN_LKG}	Leakage current into EN pin	TPS61099x	$V_{EN} = 5.0\text{ V}$			50	nA
	Overtemperature protection	TPS61099x			150		$^{\circ}\text{C}$
	Overtemperature hysteresis	TPS61099x			25		$^{\circ}\text{C}$

7.6 Typical Characteristics

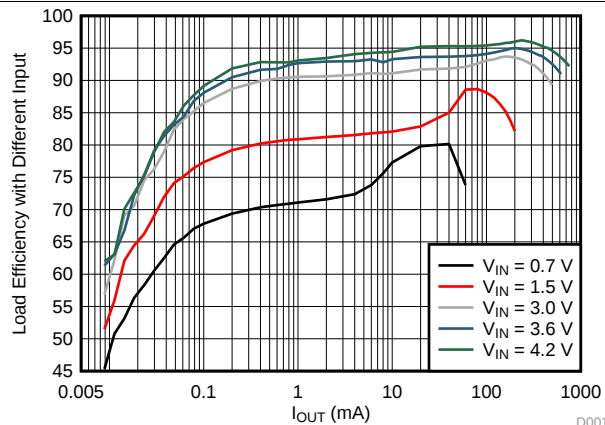


图 1. TPS61099 Load Efficiency with Different Inputs

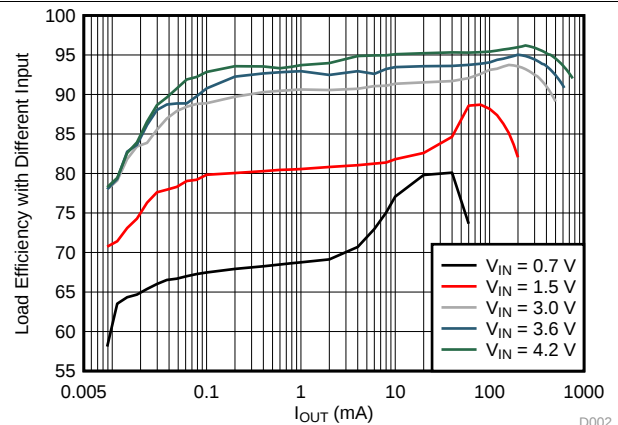


图 2. TPS610997 Load Efficiency with Different Inputs

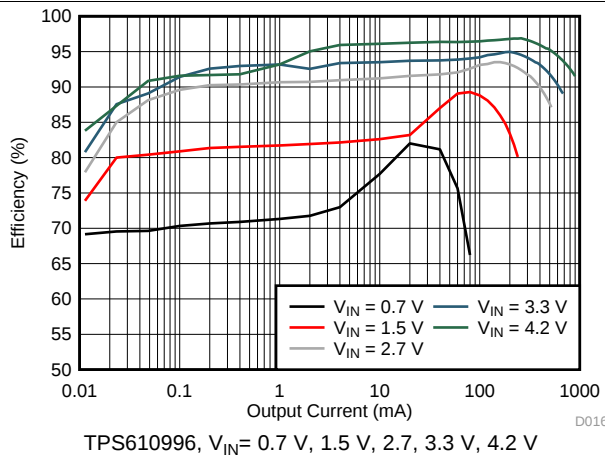


图 3. TPS610996 Load Efficiency with Different Inputs

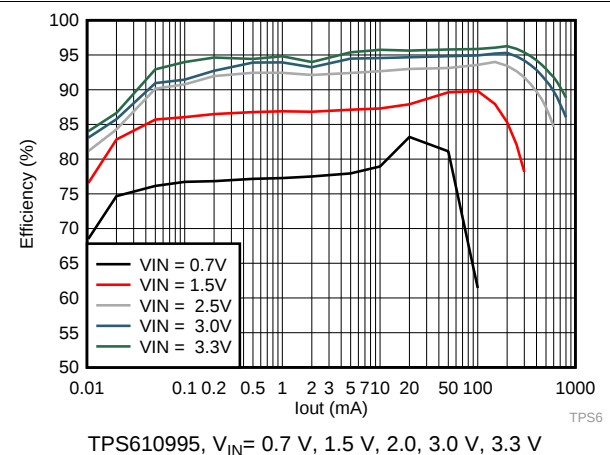


图 4. TPS610995 Load Efficiency with Different Inputs

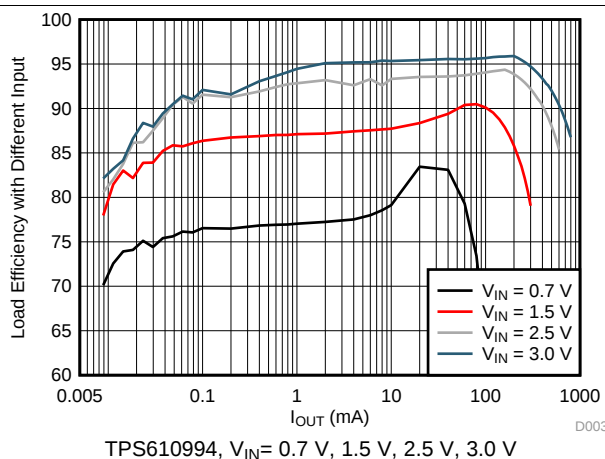


图 5. TPS610994 Load Efficiency with Different Inputs

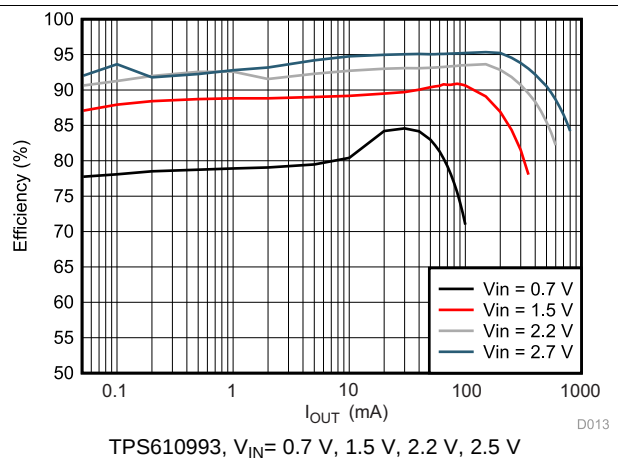
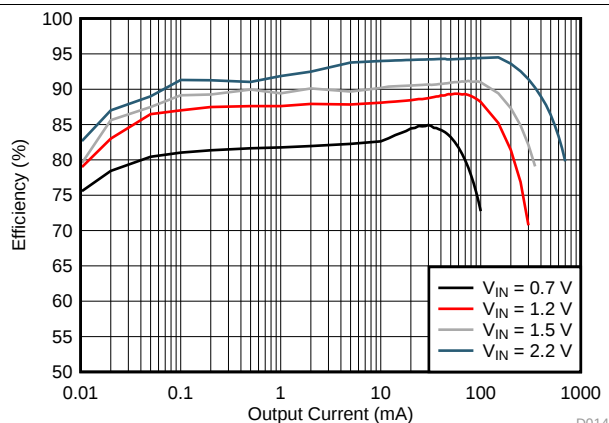


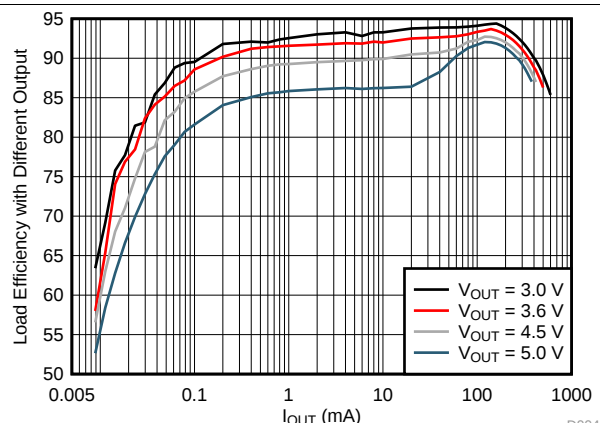
图 6. TPS610993 Load Efficiency with Different Inputs

Typical Characteristics (接下页)



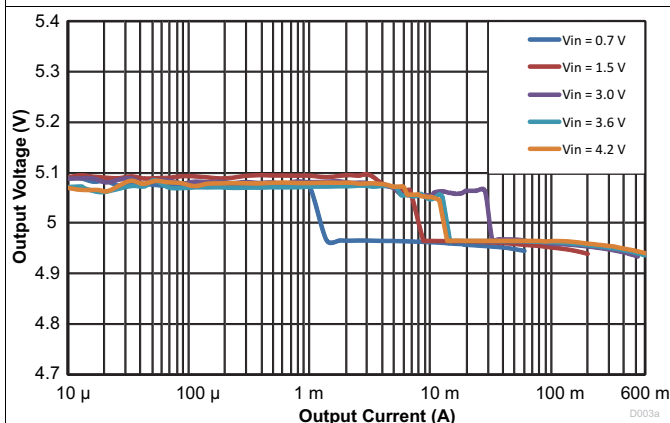
TPS610992, $V_{IN} = 0.7\text{ V}, 1.2\text{ V}, 1.5\text{ V}, 2.2\text{ V}$

图 7. TPS610992 Load Efficiency with Different Inputs



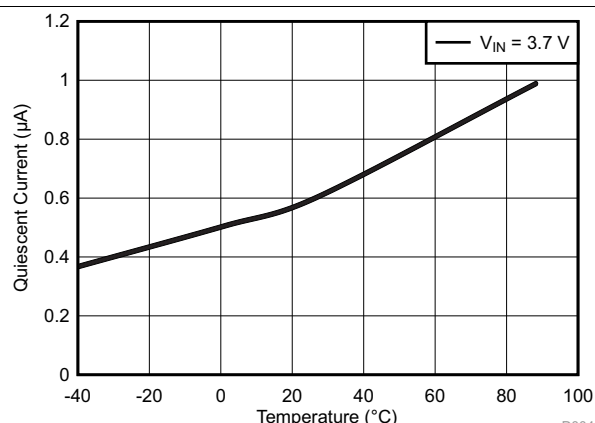
TPS61099, $V_{IN} = 2.4\text{ V}, V_{OUT} = 3.0\text{ V}, 3.6\text{ V}, 4.5\text{ V}, 5.0\text{ V}$

图 8. Load Efficiency with Different Outputs



TPS61099, $V_{IN} = 0.7\text{ V}, 1.5\text{ V}, 3.0\text{ V}, 3.6\text{ V}, 4.2\text{ V}, V_{OUT} = 5.0\text{ V}$

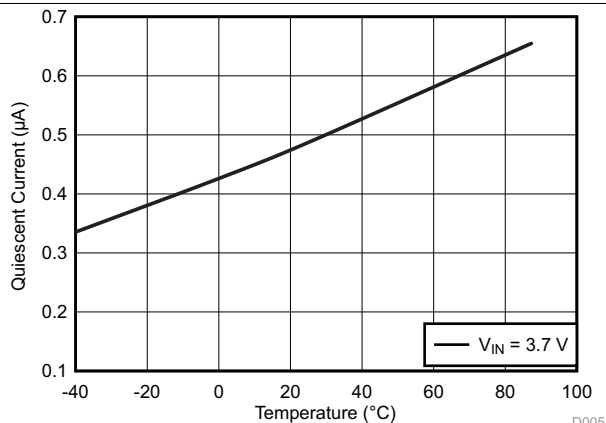
图 9. Load Regulation



$V_{IN} = 3.7\text{ V}$

No Switching

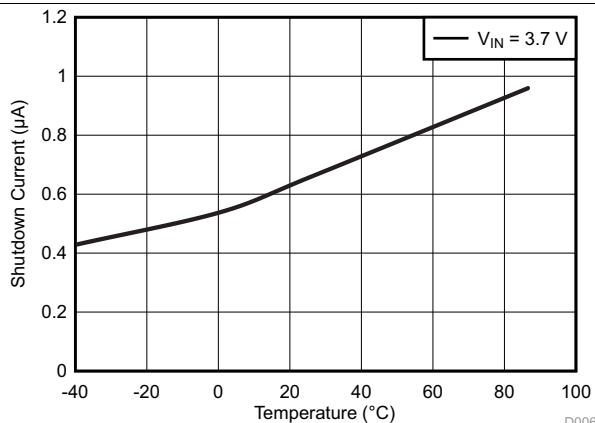
图 10. Quiescent Current into V_{OUT} vs Temperature



$V_{IN} = 3.7\text{ V}$

No Switching

图 11. Quiescent Current into V_{IN} vs Temperature



$V_{IN} = 3.7\text{ V}, \text{ Into } V_{IN} \text{ and SW}$

图 12. Shutdown Current vs Temperature

Typical Characteristics (接下页)

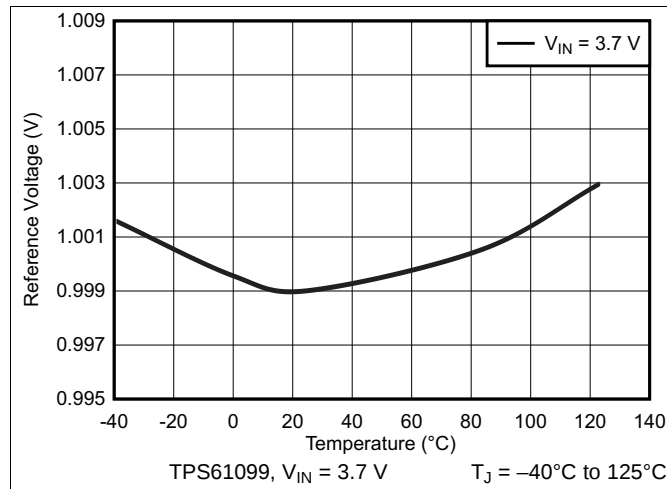


图 13. Reference Voltage vs Temperature

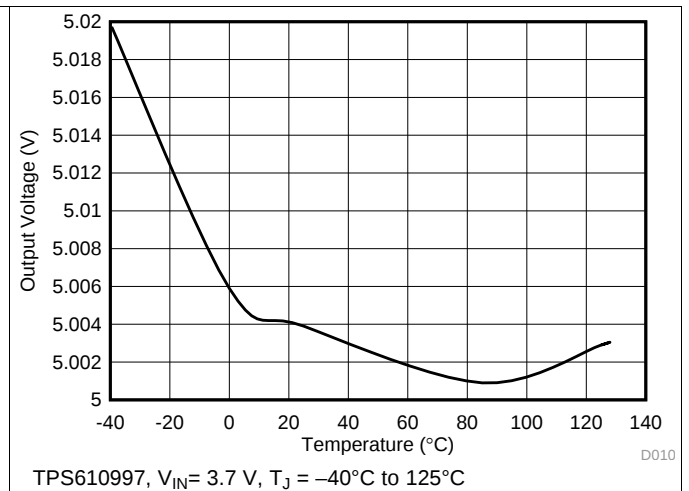


图 14. Output Voltage vs Temperature

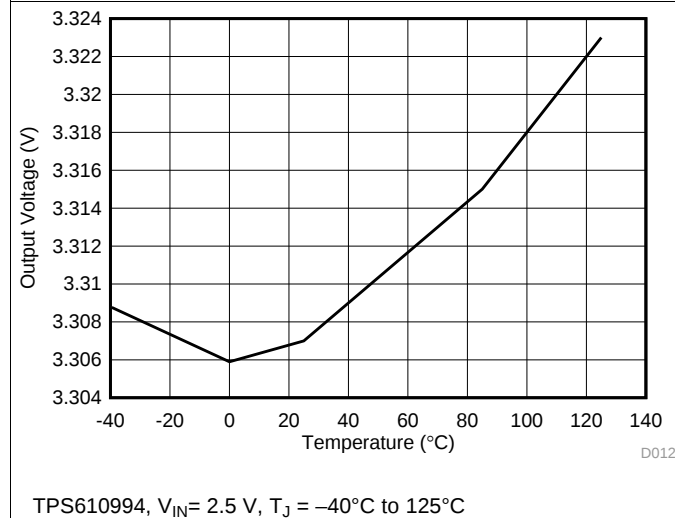


图 15. TPS610994 Output Voltage vs Temperature

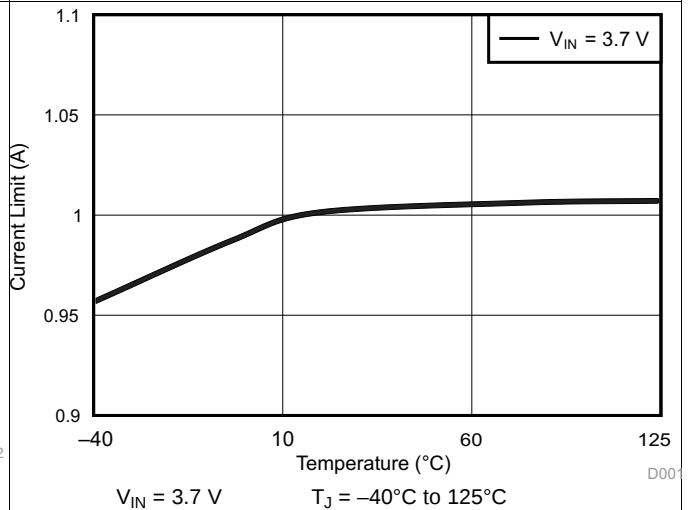


图 16. Current Limit vs Temperature

Feature Description (接下页)

boost converter enters into Burst mode. In Burst mode, the boost converter ramps up the output voltage with several switching cycles. Once the output voltage exceeds a setting threshold, the device stops switching and goes into a sleep status. In sleep status, the device consumes less quiescent current. It resumes switching when the output voltage is below the setting threshold. It exits the Burst mode when the output current can no longer be supported in this mode. Refer to 图 19 for Burst mode operation details.

To achieve high efficiency, the power stage is realized as a synchronous boost topology. The output voltage V_{OUT} is monitored via an external or internal feedback network which is connected to the voltage error amplifier. To regulate the output voltage, the voltage error amplifier compares this feedback voltage to the internal voltage reference and adjusts the required offset of the inductor current accordingly.

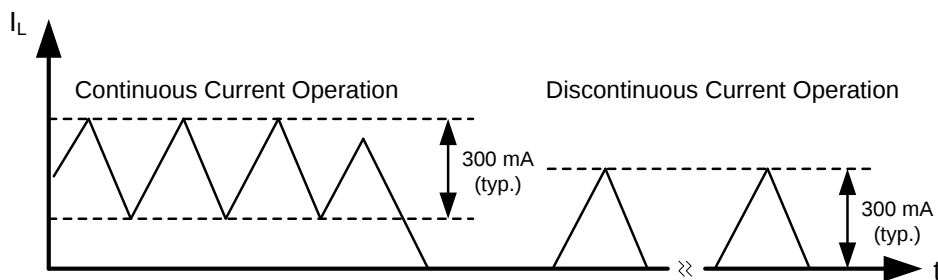


图 18. Hysteretic Current Operation

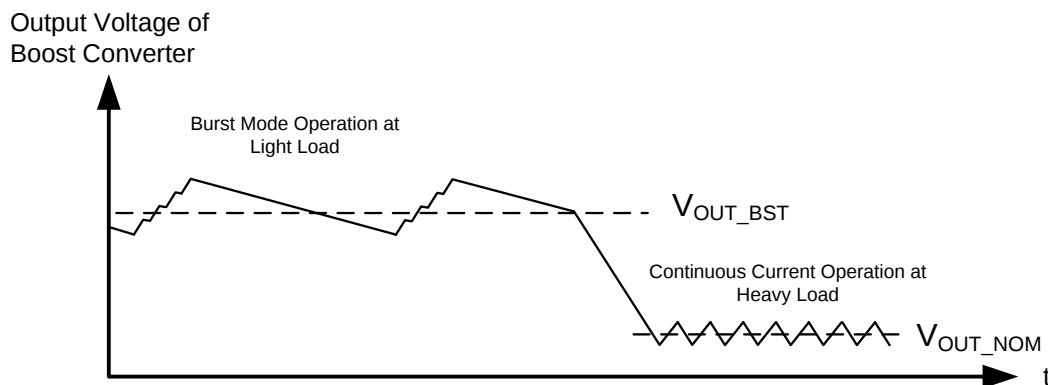


图 19. Burst Mode Operation

8.3.2 Under-Voltage Lockout

An under-voltage lockout (UVLO) circuit stops the operation of the converter when the input voltage drops below the typical UVLO threshold of 0.4 V. A hysteresis of 200 mV is added so that the device cannot be enabled again until the input voltage goes up to 0.6 V. This function is implemented in order to prevent malfunctioning of the device when the input voltage is between 0.4 V and 0.6 V.

8.3.3 Enable and Disable

When the input voltage is above UVLO rising threshold and the EN pin is pulled to high voltage, the TPS61099x is enabled. When the EN pin is pulled to low voltage, the TPS61099x goes into shutdown mode. In shutdown mode, the device stops switching and the rectifying PMOS fully turns off, providing the completed disconnection between input and output. Less than 0.5- μ A input current is consumed in shutdown mode.

Feature Description (接下页)

8.3.4 Soft Start

After the EN pin is tied to high voltage, the TPS61099x begins to startup. At the beginning, the device operates at the boundary of Discontinuous Conduction Mode (DCM) and Continuous Conduction Mode (CCM), and the inductor peak current is limited to around 200 mA during this stage. When the output voltage is charged above approximately 1.6 V, the device starts the hysteretic current mode operation. The current limit threshold is gradually increasing to $0.7 \times I_{LIM}$ within 500 μ s. In this way, the soft start function reduces the inrush current during startup. After V_{OUT} reaches the target value, soft start stage ends and the peak current is now determined by the output of an internal error amplifier which compares the feedback of the output voltage and the internal reference voltage.

The TPS61099x is able to start up with 0.7-V input voltage with larger than 3-k Ω load. However, if the load during startup is so heavy that the TPS61099x fails to charge the output voltage above 1.6 V, the TPS61099x can't start up successfully until the input voltage is increased or the load current is reduced. The startup time depends on input voltage and load current.

8.3.5 Current Limit Operation

The TPS61099x employs cycle-by-cycle over-current protection (OCP) function. If the inductor peak current reaches the current limit threshold I_{LIM} , the main switch turns off so as to stop further increase of the input current. In this case the output voltage will decrease until the power balance between input and output is achieved. If the output drops below the input voltage, the TPS61099x enters into Down Mode. The peak current is still limited by I_{LIM} cycle-by-cycle in Down Mode. If the output drops below 1.6 V, the TPS61099 enters into startup process again. In Pass-Through operation, current limit function is not enabled.

8.3.6 Output Short-to-Ground Protection

The TPS61099x starts to limit the switch current to 200 mA when the output voltage is below 1.6 V. If short-to-ground condition occurs, switch current is limited at 200 mA. Once the short circuit is released, the TPS61099x goes back to soft start again and regulates the output voltage.

8.3.7 Over Voltage Protection

TPS61099x has an output over-voltage protection (OVP) to protect the device in case that the external feedback resistor divider is wrongly populated. When the output voltage of the TPS61099 exceeds the OVP threshold of 5.8 V, the device stops switching. Once the output voltage falls 0.1 V below the OVP threshold, the device starts operating again.

8.3.8 Down Mode Regulation and Pass-Through Operation

The TPS61099x features Down Mode and Pass-Through operation when input voltage is close to or higher than output voltage.

In the Down Mode, output voltage is regulated at target value even when $V_{IN} > V_{OUT}$. The control circuit changes the behavior of the rectifying PMOS by pulling its gate to input voltage instead of to ground. In this way, the voltage drop across the PMOS is increasing as high as to regulate the output voltage. The power loss also increases in this mode, which needs to be taken into account for thermal consideration.

In the Pass-Through operation, the boost converter stops switching. The rectifying PMOS constantly turns on and low side switch constantly turns off. The output voltage is the input voltage minus the voltage drop across the dc resistance (DCR) of the inductor and the on-resistance of the rectifying PMOS.

With V_{IN} ramping up, the TPS61099x goes into Down Mode first when $V_{IN} > V_{OUT} - 50$ mV. It stays in Down Mode until $V_{IN} > V_{OUT} + 0.5$ V and then goes automatically into Pass-Through operation. In the Pass-Through operation, output voltage follows input voltage. The TPS61099x exits Pass-Through Mode and goes back to Down Mode when V_{IN} ramps down to 103% of the target output voltage. It stays in Down Mode until input voltage falls 100mV below the output voltage, returning to Boost operation.

Feature Description (接下页)

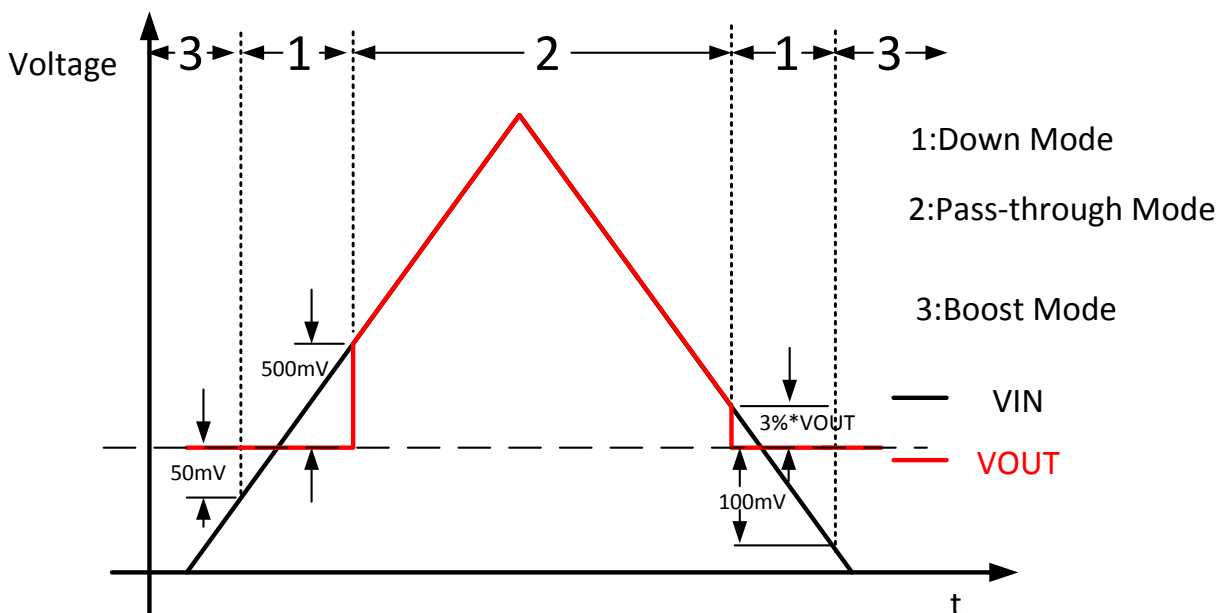


图 20. Down Mode and Pass-Through Operation

8.3.9 Thermal Shutdown

The TPS61099x has a built-in temperature sensor which monitors the internal junction temperature in boost mode operation. If the junction temperature exceeds the threshold 150°C, the device stops operating. As soon as the junction temperature drops below the shutdown temperature minus the hysteresis, typically 125°C, it starts operating again.

8.4 Device Functional Modes

8.4.1 Burst Mode Operation under Light Load Condition

The boost converter of TPS61099x enters into Burst Mode operation under light load condition. Refer to [Boost Controller Operation](#) for details.

8.4.2 Down Mode Regulation and Pass-Through Mode Operation

The boost converter of TPS61099x automatically enters into Down Mode or pass-through mode operation when input voltage is higher than the target output voltage. Refer to [Down Mode Regulation and Pass-Through Operation](#) for details.

9 Application and Implementation

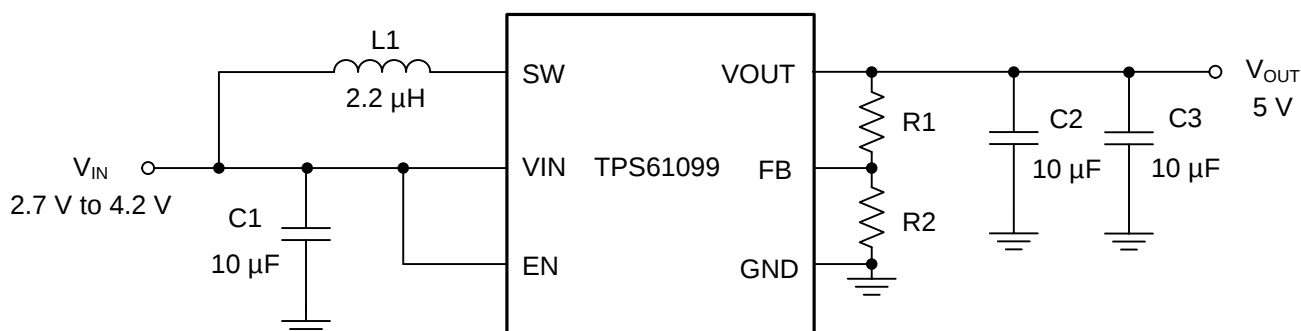
注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS61099x is a synchronous boost converter designed to operate at a wide input voltage from 0.7 V to 5.5 V with 1-A peak switch current limit. The device adopts a hysteretic control scheme so the operating frequency is not a constant value, which varies with different input/output voltages and inductor values. It only consumes 1- μ A quiescent current under light load condition. It also supports true shutdown to disconnect the load from the input in order to minimize the leakage current. Therefore, it is very suitable for alkaline battery, coin-cell battery, Li-ion or Li-polymer battery powered systems to extend the battery running time.

9.2 Typical Application - 5 V Output Boost Converter



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9.2.1 Design Requirements

A typical application example is the memory LCD, which normally requires 5-V output as its bias voltage and only consumes less than 1 mA current. The following design procedure can be used to select external component values for the TPS61099x.

表 1. Design Requirements

PARAMETERS	VALUES
Input Voltage	2.7 V ~ 4.2 V
Output Voltage	5 V
Output Current	1 mA
Output Voltage Ripple	± 50 mV

9.2.1.1 Detailed Design Procedure

9.2.1.1.1 Custom Design With WEBENCH® Tools

[Click here](#) to create a custom design using the TPS61099 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance

- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

9.2.1.1.2 Programming the Output Voltage

There are two ways to set the output voltage of the TPS61099x. For adjustable output voltage version, select the external resistor divider R1 and R2, as shown in 公式 1, the output voltage is programmed to the desired value. When the output voltage is regulated, the typical voltage at the FB pin is V_{REF} of 1.0 V.

$$V_{OUT} = V_{REF} \cdot \frac{R1 + R2}{R2} \quad (1)$$

For fixed output voltage versions, the FB pin should be connected to the GND. The TPS61099x offers diverse fixed voltage versions, refer to [Device Comparison Table](#) for version details.

In this example, 5-V output is required to bias the memory LCD. For the best accuracy, the current following through R2 should be 100 times larger than FB pin leakage current. Changing R2 towards a lower value increases the robustness against noise injection. Changing R2 towards higher values reduces the FB divider current for achieving the highest efficiency at low load currents. 1-M Ω and 249-k Ω resistors are selected for R1 and R2 in this example. High accuracy resistors are recommended for better output voltage accuracy.

9.2.1.1.3 Maximum Output Current

The maximum output capability of the TPS61099x is determined by the input to output ratio and the current limit of the boost converter. It can be estimated by 公式 2.

$$I_{OUT(max)} = \frac{V_{IN} \cdot (I_{LIM} - \frac{I_{LH}}{2}) \cdot \eta}{V_{OUT}}$$

where

- η is the conversion efficiency, use 85% for estimation
- I_{LH} is the current ripple value
- I_{LIM} is the switch current limit

(2)

Minimum input voltage, maximum boost output voltage and minimum current limit I_{LIM} should be used as the worst case condition for the estimation.

9.2.1.1.4 Inductor Selection

Because the selection of the inductor affects steady state operation, transient behavior, and loop stability, the inductor is the most important component in power regulator design. There are three important inductor specifications, inductor value, saturation current, and dc resistance (DCR).

The TPS61099x is optimized to work with inductor values between 1 μ H and 2.2 μ H. For best stability consideration, a 2.2- μ H inductor is recommended under $V_{out} > 3.0V$ condition while choosing a 1- μ H inductor for applications under $V_{out} \leq 3.0V$ condition. Follow 公式 3 and 公式 4 to calculate the inductor's peak current for the application. Depending on different load conditions, the TPS61099x works in continuous current mode or discontinuous mode. In different modes, the peak currents of the inductor are also different. 公式 3 provides an easy way to estimate whether the device works in CCM or DCM. As long as the 公式 3 is true, continuous current mode is typically established. Otherwise, discontinuous current mode is typically established.

$$\frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \times \eta} > \frac{I_{LH}}{2} \quad (3)$$

The inductor current ripple I_{LH} is fixed by design. Therefore, the peak inductor current is calculated with 公式 4.

$$I_{L,peak} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \times \eta} + \frac{I_{LH}}{2}; \text{ continuous current mode operation}$$

$$I_{L,peak} = I_{LH}; \text{ discontinuous current mode operation}$$

where

- $I_{L,peak}$ is the peak inductor current. (4)

The inductor's saturation current must be higher than the calculated peak inductor current. 表 2 lists the recommended inductors for TPS61099x device.

After choosing the inductor, the estimated switching frequency f in continuous current mode can be calculated by 公式 5. The switching frequency is not a constant value, which is determined by L , V_{IN} and V_{OUT} .

$$f = \frac{V_{IN} \cdot (V_{OUT} - V_{IN} \cdot \eta)}{L \cdot I_{LH} \cdot V_{OUT}} \quad (5)$$

表 2. List of Inductors⁽¹⁾

VOUT [V]	INDUCTANCE [μH]	SATURATION CURRENT [A]	DC RESISTANCE [mΩ]	SIZE (LxWxH)	PART NUMBER	MANUFACTURER
> 3.0	2.2	1.95	80	2.5 x 2.0 x 1.2	74404024022	Würth Elektronik
	2.2	1.7	92	2.5 x 2.0 x 1.1	LQH2HPN2R2MJR	muRata
	2.2	1.45	163	2.0 x 1.6 x 1.0	VLS201610CX-2R2M	TDK
≤ 3.0	1.0	2.6	37	2.5 x 2.0 x 1.2	74404024010	Würth Elektronik
	1.0	2.3	48	2.5 x 2.0 x 1.0	MLP2520W1R0MT0S1	TDK
	1.0	1.5	80	2.0 x 1.2 x 1.0	LQM21PN1R0MGH	muRata

(1) See [Third-Party Products](#) disclaimer

9.2.1.1.5 Capacitor Selection

For best output and input voltage filtering, low ESR X5R or X7R ceramic capacitors are recommended.

The input capacitor minimizes input voltage ripple, suppresses input voltage spikes and provides a stable system rail for the device. An input capacitor value of 10 μF is normally recommended to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. A ceramic capacitor placed as close as possible to the VIN and GND pins of the IC is recommended.

For the output capacitor of VOUT pin, small ceramic capacitors are recommended, placed as close as possible to the VOUT and GND pins of the IC. If, for any reason, the application requires the use of large capacitors which cannot be placed close to the IC, the use of a small ceramic capacitor with a capacitance value of 1 μF in parallel to the large one is recommended. This small capacitor should be placed as close as possible to the VOUT and GND pins of the IC.

From the power stage point of view, the output capacitor sets the corner frequency of the converter while the inductor creates a Right-Half-Plane-Zero. Consequently, with a larger inductor, a larger output capacitor must be used. The TPS61099x is optimized to work with the inductor from 1 μH to 2.2 μH, so the minimal output capacitor value is 20 μF (nominal value). Increasing the output capacitor makes the output ripple smaller in PWM mode.

When selecting capacitors, ceramic capacitor's derating effect under bias should be considered. Choose the right nominal capacitance by checking capacitor's DC bias characteristics. In this example, GRM188R60J106ME84D, which is a 10-μF ceramic capacitor with high effective capacitance value at DC biased condition, is selected for VOUT rail. The performance of TPS61099x is shown in [Application Curves](#) section.

9.2.1.2 Application Curves

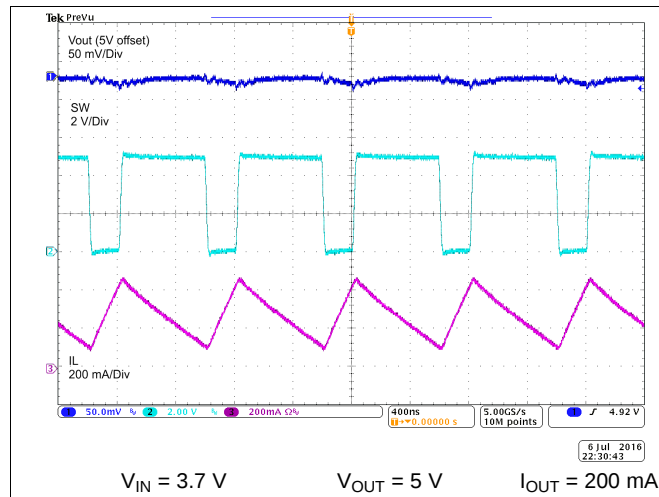


图 21. Switching Waveform at Heavy Load

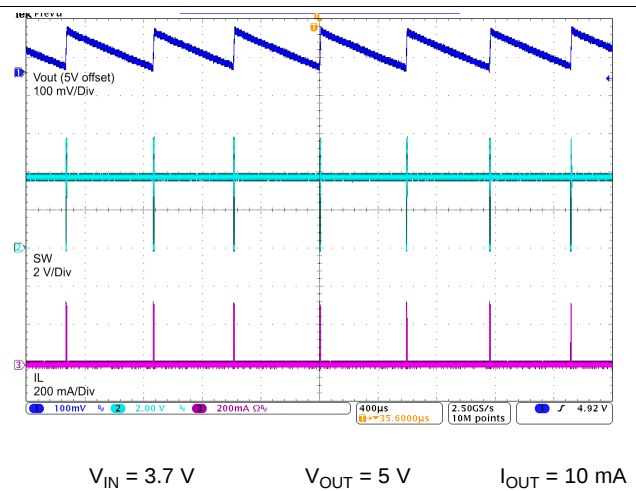


图 22. Switching Waveform at Light Load

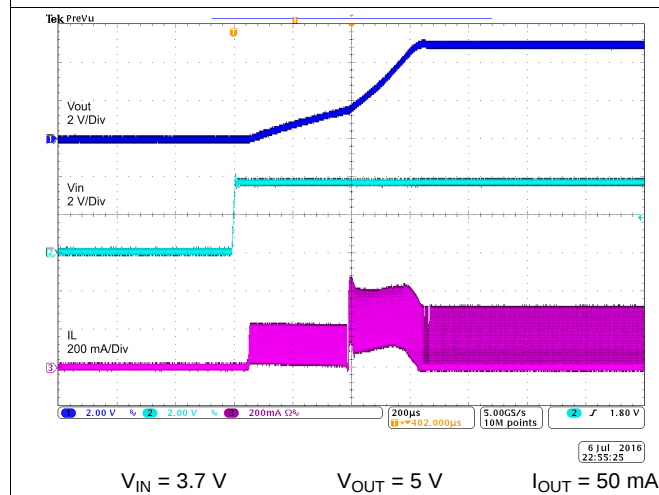


图 23. Startup by V_{IN}

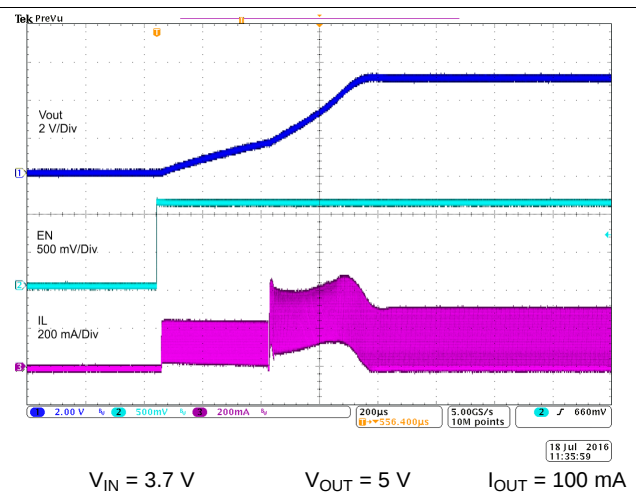


图 24. Startup by EN

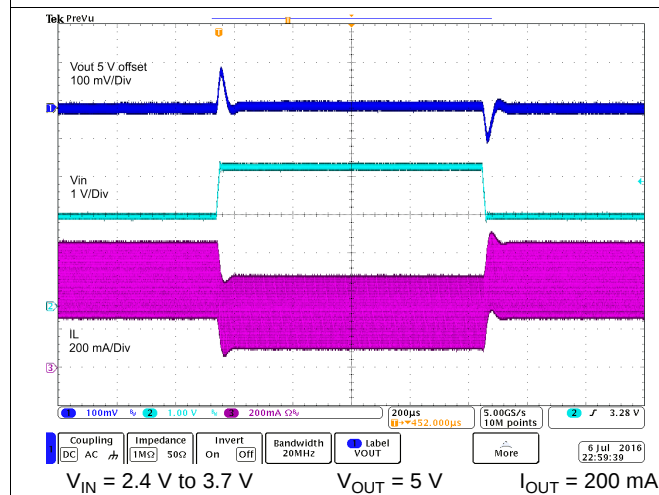


图 25. Line Transient

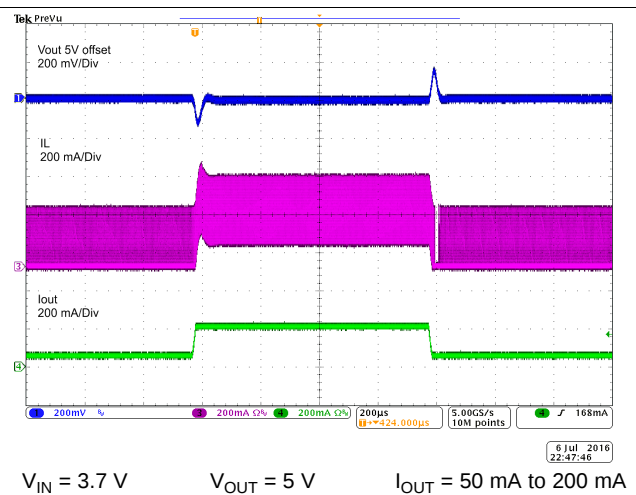
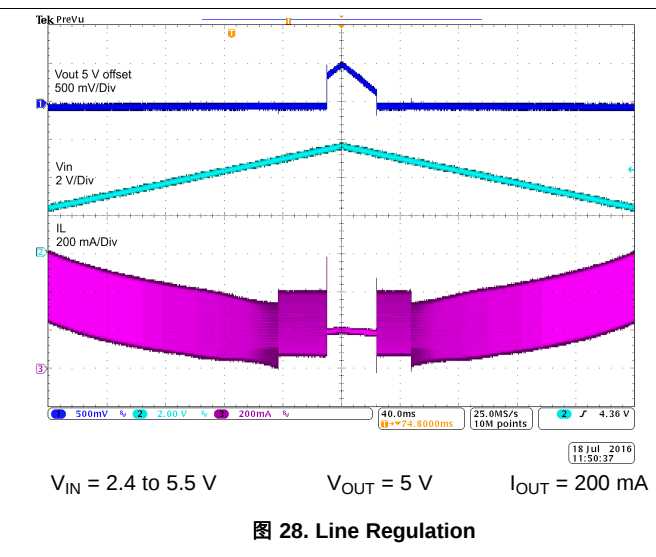
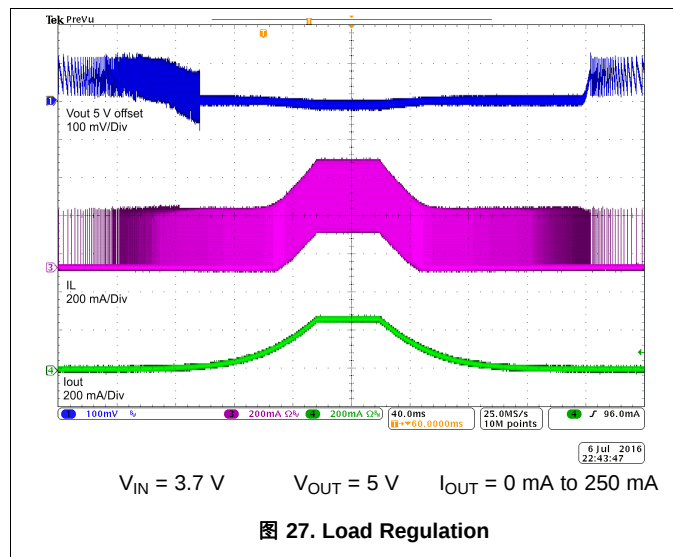


图 26. Load Transient



10 Power Supply Recommendations

The TPS61099x family is designed to operate from an input voltage supply range between 0.7 V to 5.5 V. The power supply can be alkaline battery, NiMH rechargeable battery, Li-Mn battery or rechargeable Li-Ion battery. The input supply should be well regulated with the rating of TPS61099x.

11 Layout

11.1 Layout Guidelines

As for all switching power supplies, the layout is an important step in the design, especially at high peak currents and high switching frequencies. If the layout is not carefully done, the regulator could show stability problems as well as EMI problems. Therefore, use wide and short traces for the main current path and for the power ground paths. The input and output capacitor, as well as the inductor should be placed as close as possible to the IC.

11.2 Layout Example

The bottom layer is a large GND plane connected by vias.

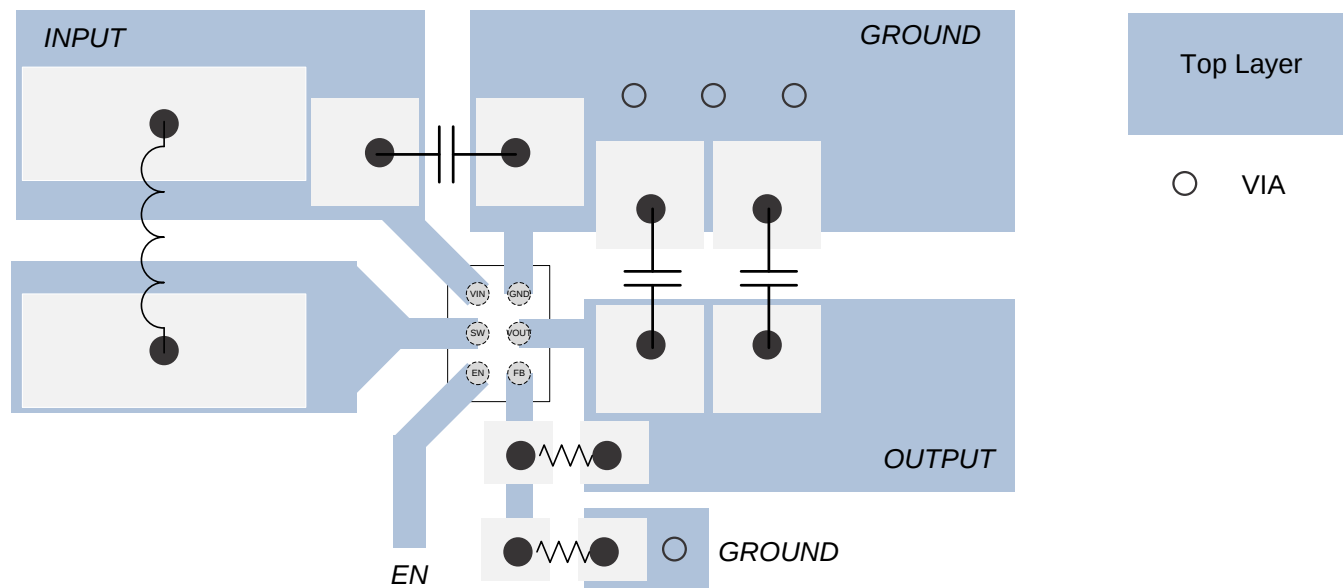


图 29. Layout -YFF

Layout Example (接下页)

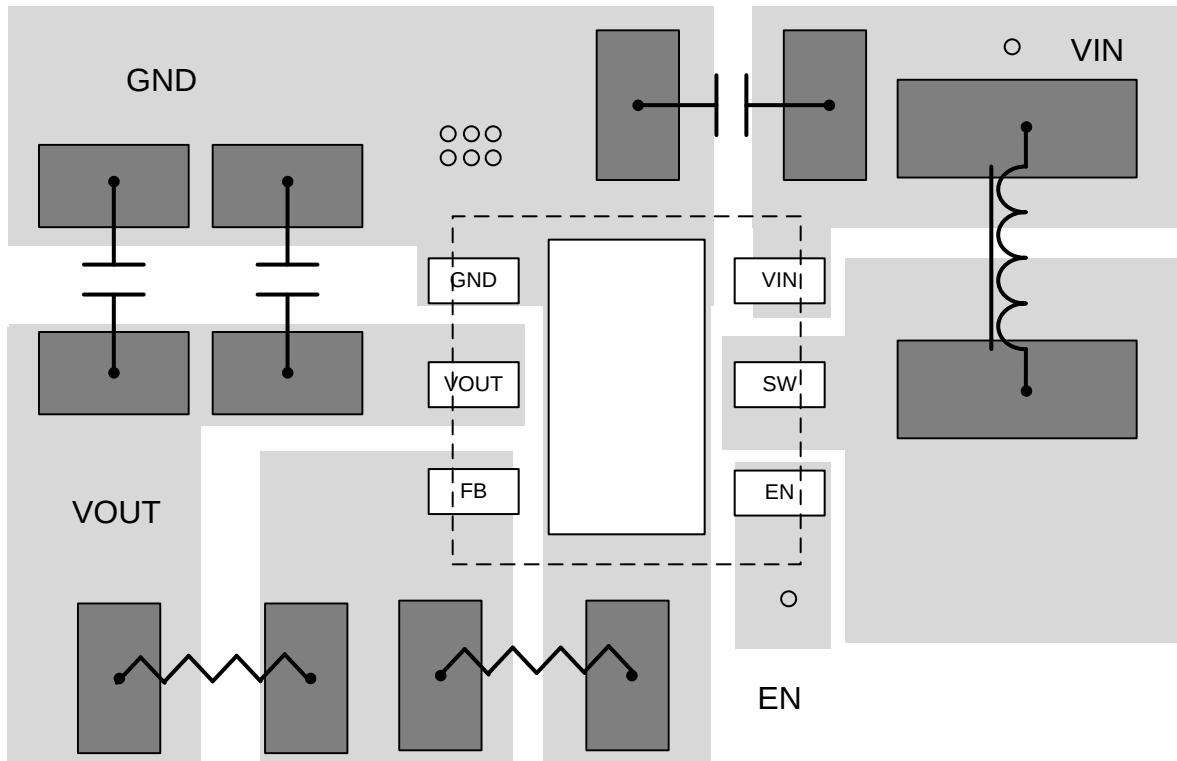


图 30. Layout - DRV

12 器件和文档支持

12.1 器件支持

12.1.1 开发支持

12.1.1.1 使用 **WEBENCH®** 工具创建定制设计

请单击[此处](#)，借助 **WEBENCH® Power Designer** 并使用 TPS61099x 器件创建定制设计方案。

1. 首先输入输入电压 (V_{IN})、输出电压 (V_{OUT}) 和输出电流 (I_{OUT}) 要求。
2. 使用优化器拨盘优化该设计的关键参数，如效率、尺寸和成本。
3. 将生成的设计与德州仪器 (TI) 的其他可行的解决方案进行比较。

WEBENCH 电源设计器可提供定制原理图以及罗列实时价格和组件供货情况的物料清单。

在多数情况下，可执行以下操作：

- 运行电气仿真，观察重要波形以及电路性能
- 运行热性能仿真，了解电路板热性能
- 将定制原理图和布局方案以常用 CAD 格式导出
- 打印设计方案的 PDF 报告并与同事共享

有关 **WEBENCH** 工具的详细信息，请访问 www.ti.com.cn/WEBENCH。

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12.2 文档支持

12.2.1 相关文档

请参阅如下相关文档：

- 《执行精确的 PFM 模式效率测量》，[SLVA236](#)
- 《精确测量超低 IQ 器件的效率》，[SLYT558](#)
- 《IQ：它是什么、不是什么以及如何使用》，[SLYT412](#)

12.3 接收文档更新通知

要接收文档更新通知，请导航至 TI.com.cn 上的器件产品文件夹。单击右上角的 **通知我** 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

12.4 社区资源

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12.5 商标

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这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

12.7 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、缩写和定义。

13 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此产品说明书的浏览器版本，请查阅左侧的导航栏。

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS610992YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19J	Samples
TPS610992YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19J	Samples
TPS610993YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17X	Samples
TPS610993YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17X	Samples
TPS610994YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17N	Samples
TPS610994YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	17N	Samples
TPS610995DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1NDU	Samples
TPS610995DRVT	ACTIVE	WSON	DRV	6	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1NDU	Samples
TPS610995YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19K	Samples
TPS610995YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19K	Samples
TPS610996YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19I	Samples
TPS610996YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	19I	Samples
TPS610997YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	14K	Samples
TPS610997YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	14K	Samples
TPS61099DRVR	ACTIVE	WSON	DRV	6	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 150	1I8U	Samples
TPS61099YFFR	ACTIVE	DSBGA	YFF	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	12G	Samples
TPS61099YFFT	ACTIVE	DSBGA	YFF	6	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	12G	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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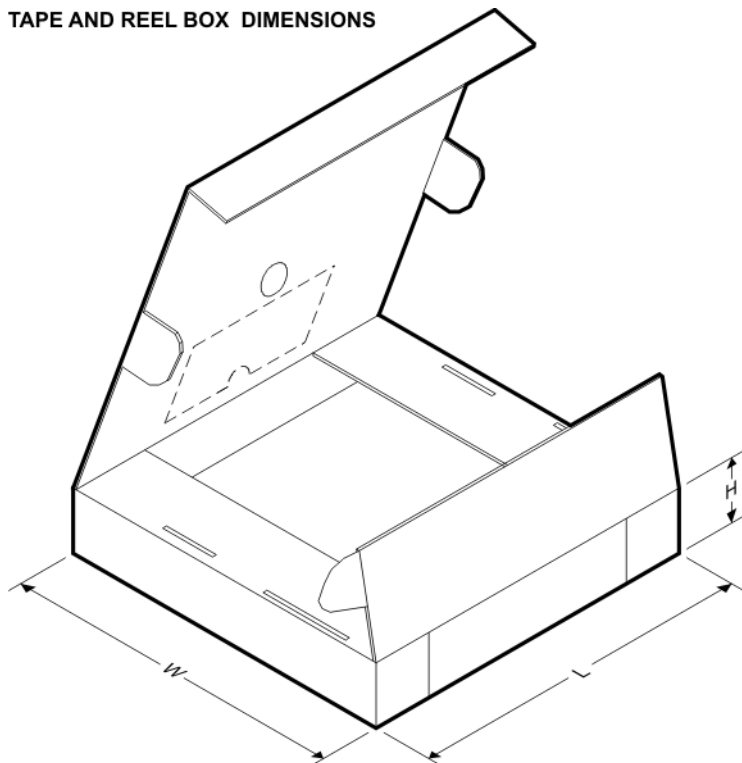
TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS610992YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610992YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610993YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610993YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610994YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610994YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610995DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS610995DRVT	WSON	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS610995YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610995YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610996YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610996YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610997YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS610997YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS61099DRVR	WSON	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS61099YFFR	DSBGA	YFF	6	3000	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1
TPS61099YFFT	DSBGA	YFF	6	250	180.0	8.4	0.96	1.36	0.69	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

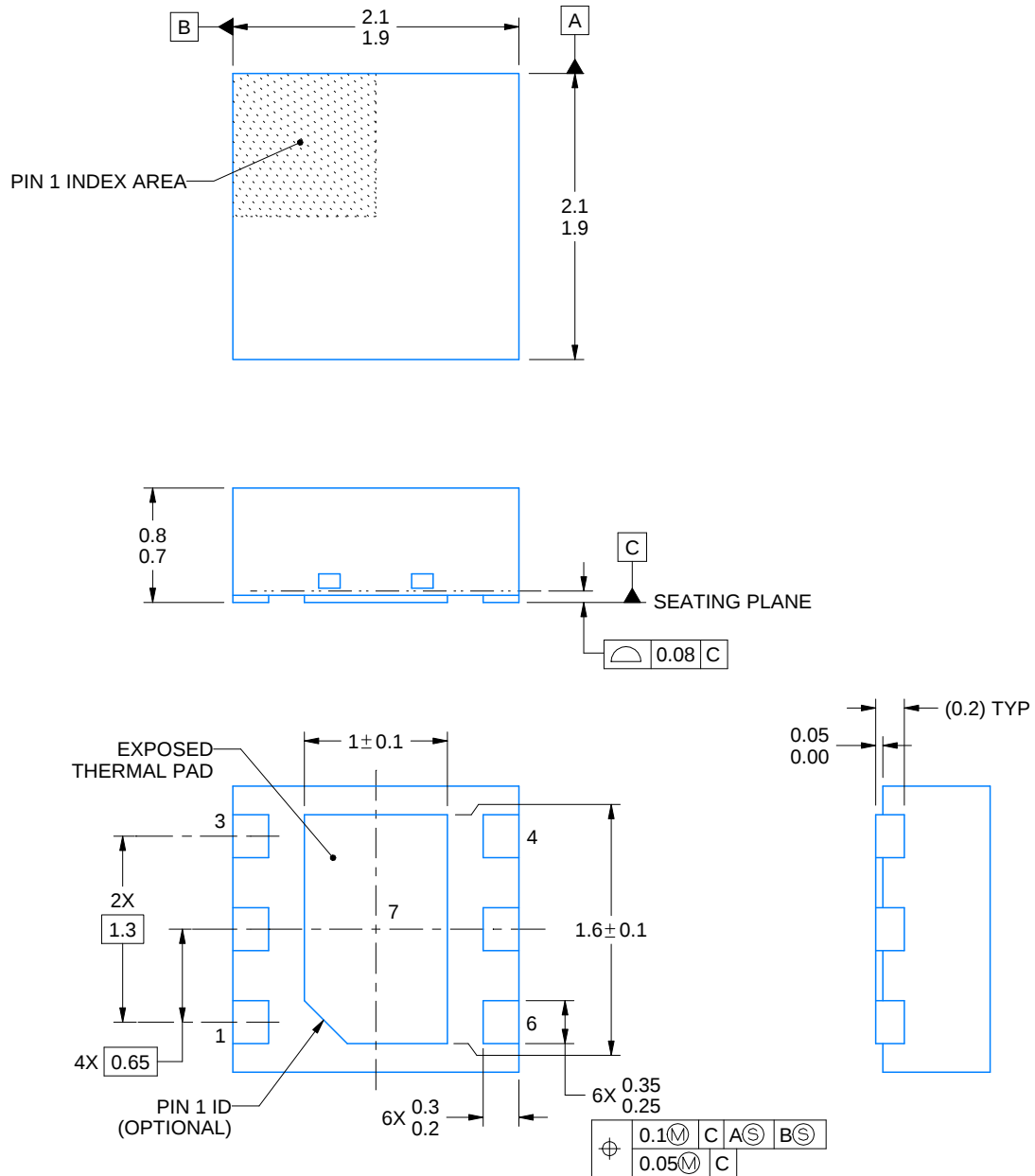


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS610992YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610992YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS610993YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610993YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS610994YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610994YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS610995DRVR	WSON	DRV	6	3000	210.0	185.0	35.0
TPS610995DRVT	WSON	DRV	6	250	210.0	185.0	35.0
TPS610995YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610995YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS610996YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610996YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS610997YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS610997YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0
TPS61099DRVR	WSON	DRV	6	3000	210.0	185.0	35.0
TPS61099YFFR	DSBGA	YFF	6	3000	182.0	182.0	20.0
TPS61099YFFT	DSBGA	YFF	6	250	182.0	182.0	20.0



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

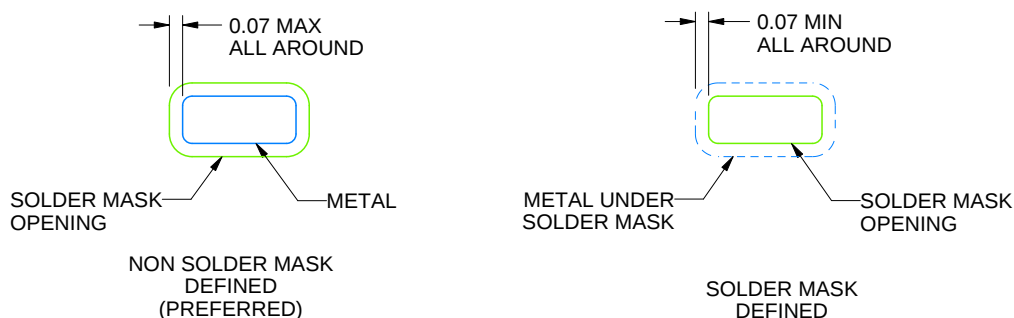
DRV0006A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:25X



SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006A

WSO - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

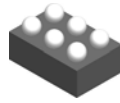
EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

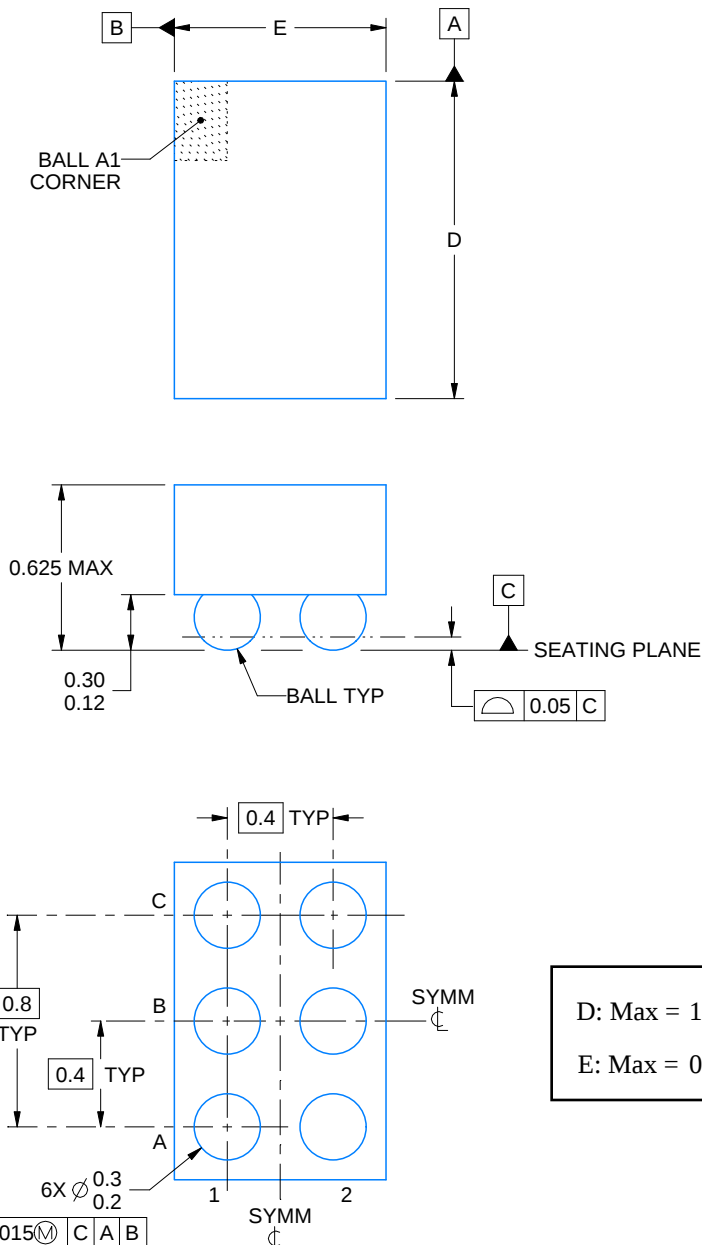
YFF0006



PACKAGE OUTLINE

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



D: Max = 1.256 mm, Min = 1.196 mm

E: Max = 0.914 mm, Min = 0.854 mm

4223785/A 06/2017

NOTES:

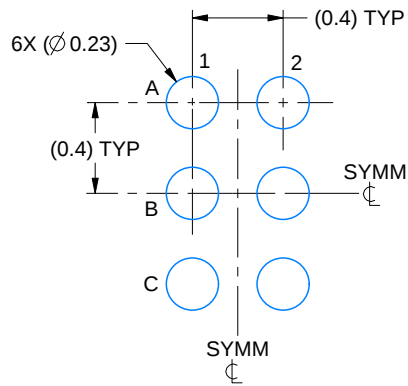
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

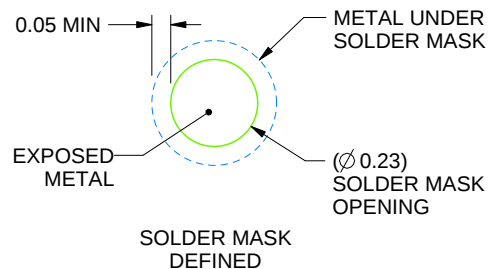
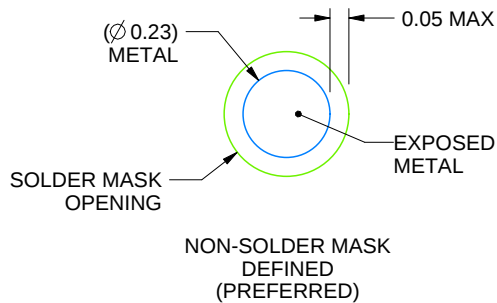
YFF0006

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:30X



SOLDER MASK DETAILS
NOT TO SCALE

4223785/A 06/2017

NOTES: (continued)

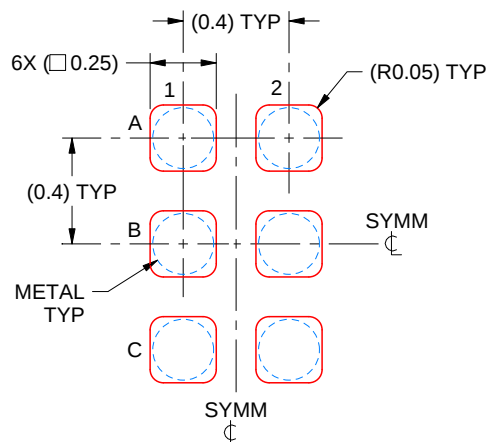
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YFF0006

DSBGA - 0.625 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:35X

4223785/A 06/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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